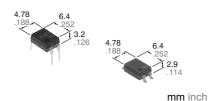


Panasonic ideas for life

General use and economy type. DIP (1 Form B) 4-pin type. Reinforced insulation 5,000V type.

GU-E PhotoMOS (AQY41OEH)

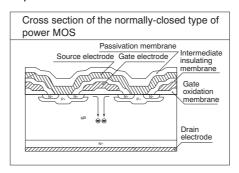


The attainment of economical pricing will broaden its market even further.

3. Normally closed type (1 Form B) is low on-resistance.

(All AQO4 PhotoMOS are Form B types. And also the Form A types have a low on-resistance.)

This has been realized thanks to the built-in MOSFET processed by our proprietary method, DSD (Double-diffused and Selective Doping) method. Cross section of the normally-closed type of power MOS



4. Reinforced insulation 5,000 V type More than 0.4 mm internal insulation distance between inputs and outputs. Conforms to EN41003, EN60950 (reinforced insulation).

5. Compact 4-pin DIP size

The device comes in a compact (W)6.4×(L)4.78×(H)3.2mm (W).252×(L).188×(H).126inch, 4-pin DIP size

- **6. Controls low-level analog signals** PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.
- 7. High sensitivity, low ON resistance Can control a maximum 0.13 A load current with a 5 mA input current. Low ON resistance of 18Ω (AQY410EH). Stable operation because there are no metallic contact parts.
- 6. Low-level off-state leakage current

TYPICAL APPLICATIONS

- Power supply
- · Measuring equipment
- Security equipment
- Modem
- Telephone equipment
- · Electricity, plant equipment
- Sensors

AQY410EH

350V

0.13A

1. 60V type couples high capacity

(0.55A) with low on-resistance (1 Ω)

GU-E type

AQY412EH

60V

0.55A

2. This is the low-cost version PhotoMOS 1 Form B output type relay.

TYPES

Item

Part No.

Load voltage

Continuous

FEATURES

	I/O isolation voltage	Output rating*			Pa				
Type				Through hole terminal Surface-mount terminal			Packing quantity		
Type		Load Load				Tape and reel packing style			Tape and
		Load voltage		Tube pac	king style	Picked from the 1/2-pin side	Picked from the 3/4-pin side	Tube	reel
AC/DC type	Reinforced 5,000 V	60 V	550 mA	AQY412EH	AQY412EHA	AQY412EHAX	AQY412EHAZ	1 to be contained 100 mass	1,000 pcs.
		350 V	130 mA	AQY410EH	AQY410EHA	AQY410EHAX	AQY410EHAZ	1 tube contains 100 pcs. 1 batch contains 1,000 pcs.	
		400 V	120 mA	AQY414EH	AQY414EHA	AQY414EHAX	AQY414EHAZ	T bater contains 1,000 pcs.	

^{*}Indicate the peak AC and DC values.

Note: For space reasons, the initial letters of the part number "AQY", the SMD terminal shape indicator "A" and the package style indicator "X" or "Z" are not marked on the relay.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY412EH (A)	AQY410EH (A)	AQY414EH (A)	Remarks
	LED forward current	lF	50 mA			
Innut	LED reverse voltage	VR		5 V		
Input	Peak forward current	IFP	1 A			f = 100 Hz, Duty factor = 0.1%
	Power dissipation	Pin	75 mW			
	Load voltage (peak AC)	VL	60 V	350 V	400 V	
Output	Continuous load current	Iι	0.55 A	0.13 A	0.12 A	
Output	Peak load current	Ipeak	1.5 A	0.4 A	0.3 A	100 ms (1 shot), V∟= DC
	Power dissipation	Pout	500 mW			
Total po	Total power dissipation			550 mW		
I/O isola	I/O isolation voltage			5,000 V AC		
Temper	ature Operating	Topr	-40°C to +85°C -40°F to +185°F			Non-condensing at low temperatures
limits	Storage	Tstg	-40°C	to +100°C -40°F to +		

GU-E PhotoMOS (AQY41OEH)

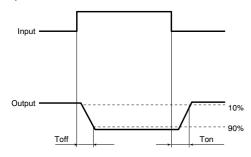
2. Electrical characteristics (Ambient temperature: 25°C 77°F)

	Item		Symbol	AQY412EH (A)	AQY410EH (A)	AQY414EH (A)	Condition
	LED operate (OFF) current	Typical	1		I∟=Max.		
		Maximum	Foff				
Innut	LED reverse (ON) current	Minimum	IFon		I∟=Max.		
Input		Typical	IFon				
	LED dropout voltage	Typical	VF	1.:	I _F = 50 mA		
		Maximum	VF				
	On resistance	Typical	Ron	1Ω	18Ω	26Ω	I _F = 0 mA I _L = Max.
Output		Maximum		2.5Ω	25Ω	35Ω	Within 1 s on time
·	Off state leakage current	Maximum	Leak	10μΑ			I₅ = 5 mA V∟ = Max.
	Operate (OFF) time*	Typical	Toff	3.0 ms	1.0 ms	0.8 ms	I _F = 0 mA > 5 mA
		Maximum	I off	10.0 ms 3.0 ms			I∟ = Max.
	Reverse (ON) time*	Typical	Ton	0.2 ms	0.3 ms	0.2 ms	I _F = 5 mA > 0 mA
Transfer		Maximum	I on		I∟ = Max.		
characteristics	I/O conscitance	Typical	Ciso	0.8 pF			f = 1MHz $V_B = 0 V$
	I/O capacitance	Maximum	Oiso	1.5 pF			
	Initial I/O isolation resistance	Minimum	Riso	1,000ΜΩ			500 V DC

Note: Recommendable LED forward current I_F = 5 to 10mA.

Type of connection

*Operate/Reverse time

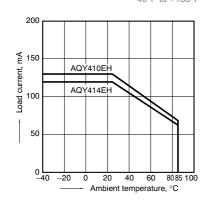


- **Dimensions**
- **Schematic and Wiring Diagrams**
- **■** Cautions for Use

REFERENCE DATA

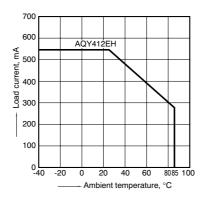
1-(1). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C



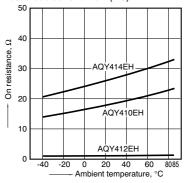
1-(2). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C -40°F to +185°F



2. On resistance vs. ambient temperature characteristics

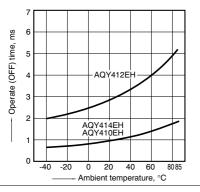
Measured portion: between terminals 3 and 4; LED current: 0 mA; Load voltage: Max.(DC); Continuous load current: Max. (DC)



GU-E PhotoMOS (AQY41OEH)

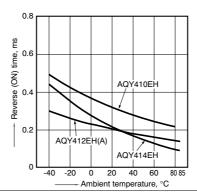
3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



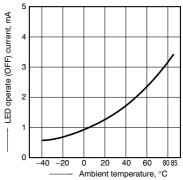
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



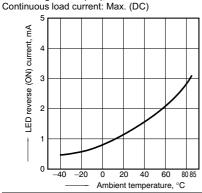
5. LED operate (OFF) current vs. ambient temperature characteristics Sample: All types;

Load voltage: Max. (DC); Continuous load current: Max. (DC)

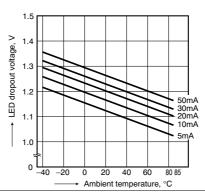


6. LED reverse (ON) current vs. ambient temperature characteristics

Sample: All types; Load voltage: Max. (DC);

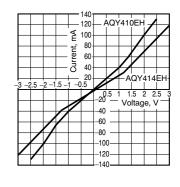


7. LED dropout voltage vs. ambient temperature characteristics LED current: 5 to 50 mA



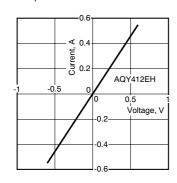
8-(1). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



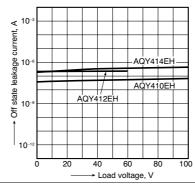
$8\mbox{-}(2).$ Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C $77^{\circ}F$



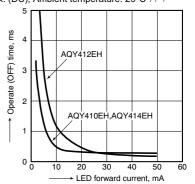
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



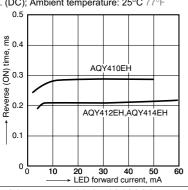
10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: $25^{\circ}C$ $77^{\circ}F$



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4; Frequency: 1 MHz; Ambient temperature: 25°C 77°F

